Preliminary studies on 3D Diamond

Alexander Oh CARAT Workshop

Research Interest

- 3D diamond detectors
 - Grain boundaries
 - Refined Modeling
 - Bulk electrodes
- Radiation Damage
- Spatially resolved measurements of charge transport
 - test beams







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Why 3D?

 Silicon results show radiation hardness increases for 3D geometry.





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- Beamtime 2010
 - Alexander Oh (PI), Cinzia Da Via, Mahfuza Ahmed, Thorsten Wengler, Steven Watts
- Use 15 keV photons to create charge in a diamond detector.
- Two field \bullet configurations
- Device is • 1 x 1 x 3 mm³



Samples & Data

- Samples provided by DDL
- "dot" electrodes
- Samples investigated
 - pCVD 1mm x 1mm x 3mm, Top Bottom Electrodes
 - pCVD 1mm x 1mm x 3mm, Left Right Electrodes
 - sCVD 1mm x 1mm x 2mm
- Data taken:
 - line scans at different voltages, both polarities
 - full scan, fixed field, both polarities
 - the above for beam parallel and orthogonal to electric field
- pCVD unfortunately excessive leakage current.



Beam-line

 at the
 Diamond
 Synchrotron
 Light Facility



Beam Line

- Energy: 15 keV
- Absorption length ~3.5mm (total), ~18mm (photoelectric absorption)
- Beam focus: compound refractive lense
- Beam size: 4mum FWHM
- Flux: ~ 10^9 photons/s
- Very good Beam Line Support!
 - Technician
 - Beamline physicist
 - Fully working DAQ setup (plug & play)

 Single Crystal Diamond sample glued to the test PCB



- Simple set-up
- Experimental table can move in theta, phi, x, y, z.
- Automatic scans via DAQ system.



 Polycrystalline diamond samples









- Surface scan with 10mum step size.
- Charge collected laterally across grain boundaries.
- Collected lots of data to analyse!
- First preliminary findings:



-9.15

.9.25

.93

fine scan

step size

2mum

- Area scans for pCVD-LR, E parallel
- Field E=1kV/cm
- Negative and positive field



- Area scans for pCVD-LR, E orthogonal
- Field E=1kV/cm
- Negative and positive field



- Area scans for pCVD-TB, E parallel
- Field E=0.5kV/cm
- Negative field



- Area scans for pCVD-TB, E ortogonal
- Field E=0.5kV/cm
- Negative and positive field



- Response along a line for different voltages for sample B.
- Comparison of sample A and sample B.
 - 40% 70% less signal for sample B.
- Grain boundaries seem to have a detrimental effect on charge collection.



- Multiple line scans to measure the pumping behavior spatially resolved.
- Is the priming uniform?
- Extract priming parameters as a function of position.

$$f(n) = a + b \cdot \left(1 - e^{-\frac{n}{c}}\right)$$



- Large variations observed with position.
- No clear correlation of priming parameters and signal response

$$f(n) = a + b \cdot \left(1 - e^{-\frac{n}{c}}\right)$$



Outlook

- Analysis ongoing.
- Successfully applied for beam time in 2011
- Further investigations:
 - Angular scans
 - working sCVD
 - varying width samples
 - Graphite electrodes









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